## Old Company Name in Catalogs and Other Documents

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## MOS FIELD EFFECT TRANSISTOR

# $\mu$ PA654TT

## P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

#### **DESCRIPTION**

The  $\mu$ PA654TT is a switching device, which can be driven directly by a 1.8 V power source, and it is suitable for applications such as power switch of portable equipment and so on.

#### **FEATURES**

- 1.8 V drive available
- Low on-state resistance

RDS(on)1 = 88 m $\Omega$  MAX. (VGS = -4.5 V, ID = -1.5 A)

 $R_{DS(on)2} = 133 \text{ m}\Omega \text{ MAX}. \text{ (V}_{GS} = -2.5 \text{ V}, I_{D} = -1.5 \text{ A})$ 

 $R_{DS(on)3} = 234 \text{ m}\Omega \text{ MAX.} (V_{GS} = -1.8 \text{ V}, I_{D} = -1.0 \text{ A})$ 

#### ORDERING INFORMATION

PART NUMBER	PACKAGE		
μPA654TT-E1-A	Cn::n\MCOF (4020)		
μPA654TT-E2-A	6pinWSOF (1620)		

#### Marking: WH

**Remark** "-A"indicates Pb-free (This product does not contain Pb in external electrode and other parts.). "-E1", "-E2"indicates the unit orientation. (8 mm embossed carrier tape, 3000 pcs/reel)

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

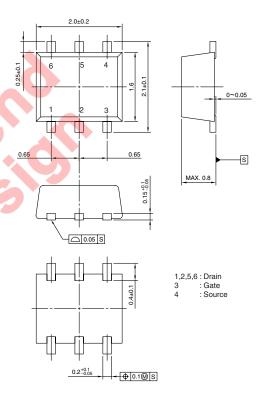
Drain to Source Voltage (Ves = 0 V)	VDSS	-12	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	Vgss	∓8.0	V
Drain Current (DC) Note1	I <sub>D(DC)</sub>	∓2.5	Α
Drain Current (pulse) Note2	ID(pulse)	∓10	Α
Total Power Dissipation 1	P <sub>T1</sub>	0.2	W
Total Power Dissipation 2 Note1	P <sub>T2</sub>	1.3	W
Channel Temperature	$T_ch$	150	°C
Storage Temperature	Tstg	-55 to +150	°C

**Notes 1.** Mounted on FR-4 board of 5000 mm<sup>2</sup> x 1.1 mm,  $t \le 5$  sec.

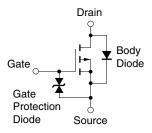
sales representative for availability and additional information.

**2.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

#### PACKAGE DRAWING (Unit: mm)



#### **EQUIVALENT CIRCUIT**



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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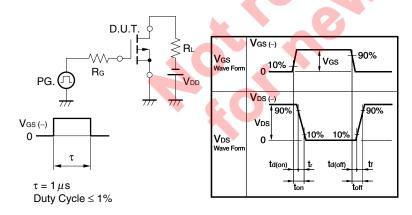
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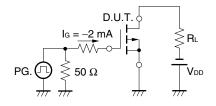
### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

	1	<del>r'</del>				
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	loss	V <sub>DS</sub> = -12 V, V <sub>GS</sub> = 0 V			-10	μΑ
Gate Leakage Current	Igss	$V_{GS} = \mp 8.0 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.0 mA	-0.45	-0.75	-1.5	V
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = -10 V, I <sub>D</sub> = -1.5 A	1.0	4.7		S
Drain to Source On-state Resistance	RDS(on)1	V <sub>GS</sub> = -4.5 V, I <sub>D</sub> = -1.5 A		70	88	mΩ
	RDS(on)2	V <sub>GS</sub> = -2.5 V, I <sub>D</sub> = -1.5 A		100	133	mΩ
	R <sub>DS(on)3</sub>	V <sub>GS</sub> = -1.8 V, I <sub>D</sub> = -1.0 A		140	234	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = -10 V		250		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		83		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		40		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = -6.0 V, I <sub>D</sub> = -1.5 A		16		ns
Rise Time	<b>t</b> r	V <sub>GS</sub> = -4.0 V		90		ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 10 Ω		173		ns
Fall Time	t <sub>f</sub>			138		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = -10 V	<b>5</b> )	2.7		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = -4.0 V		0.5		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = -2.5 A		0.8		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	I <sub>F</sub> = 2.5 A, V <sub>GS</sub> = 0 V		0.87		V

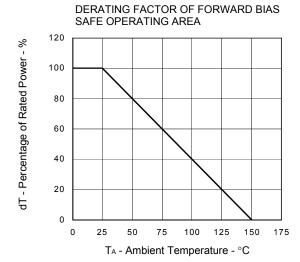
#### **TEST CIRCUIT 1 SWITCHING TIME**



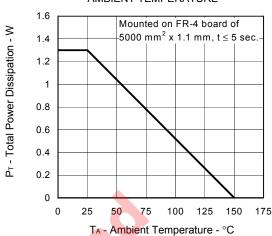
#### **TEST CIRCUIT 2 GATE CHARGE**



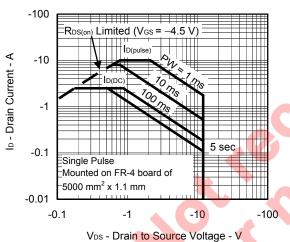
#### TYPICAL CHARACTERISTICS (TA = 25°C)



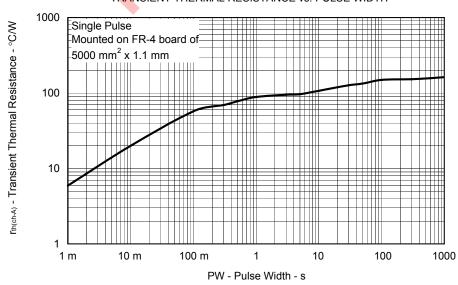
#### TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



#### FORWARD BIAS SAFE OPERATING AREA

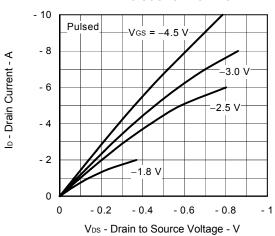




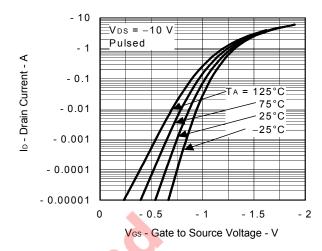


3

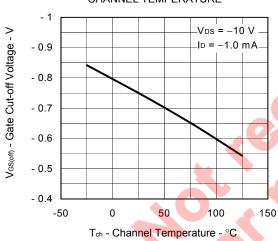
## DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



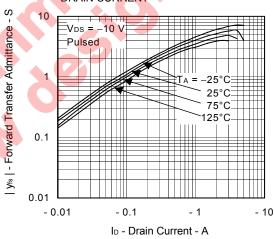
#### FORWARD TRANSFER CHARACTERISTICS



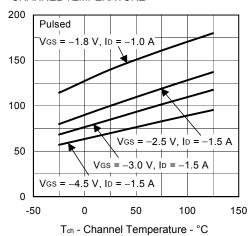
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



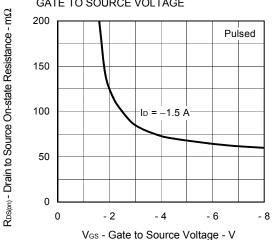
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



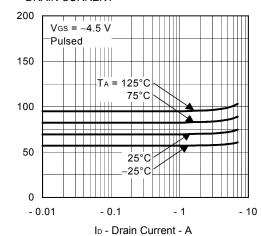
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



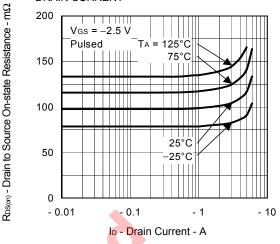
R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

 $\mathsf{R}_{\mathsf{DS}(m)}$  - Drain to Source On-state Resistance -  $m\Omega$ 

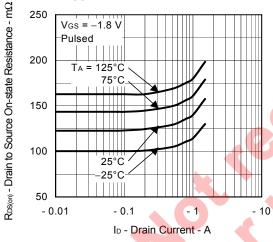
## DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



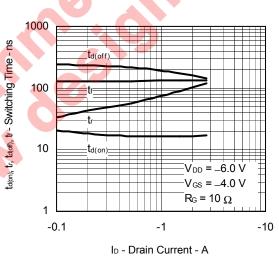
## DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



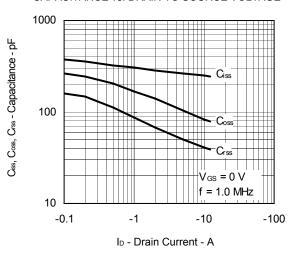
## DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



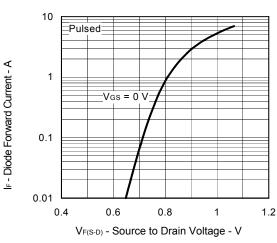
#### SWITCHING CHARACTERISTICS

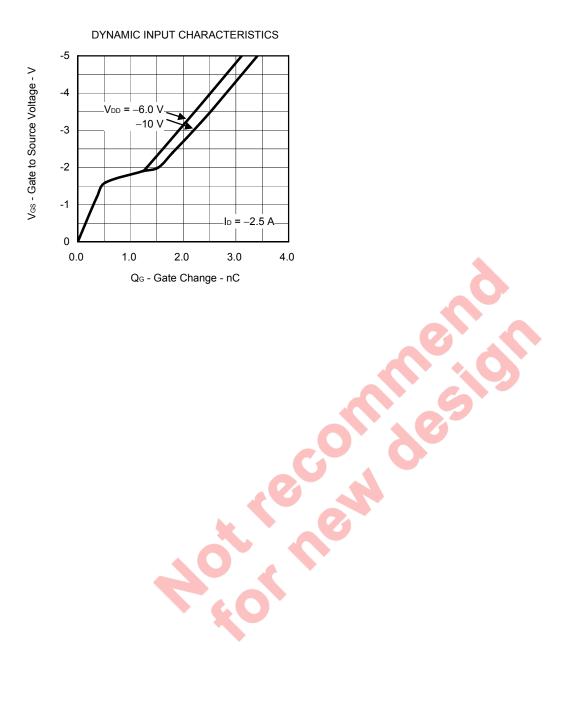


#### CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE





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